



DMN2024UFDF

# 20V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

| BV <sub>DSS</sub> | Rds(on) Max                   | I <sub>D</sub> Max<br>T <sub>A</sub> = +25°C |
|-------------------|-------------------------------|--|
|                   | $22m\Omega @ V_{GS} = 4.5V$   | 7.1A   |
| 2017              | $26m\Omega @ V_{GS} = 2.5V$   | 6.5A   |
| 20V               | 36mΩ @ Vgs = 1.8V             | 5.5A   |
|                   | 50mΩ @ V <sub>GS</sub> = 1.5V | 4.7A   |

#### Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

# Applications

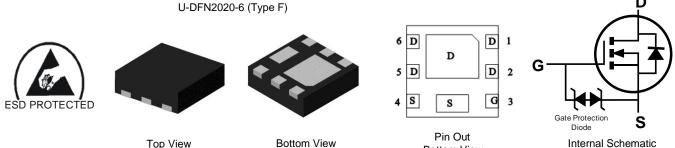
- Battery Management Application
- **Power Management Functions**
- **DC-DC** Converters

#### **Features**

- 0.6mm Profile—Ideal for Low Profile Applications
- PCB Footprint of 4mm<sup>2</sup> •
- Low Gate Threshold Voltage
- Fast Switching Speed
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

- Case: U-DFN2020-6 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.0065 grams (Approximate)



**Bottom View** 

Internal Schematic

#### Ordering Information (Note 4)

| Part Number    | Reel Size (inches) | Quantity Per Reel |
|----------------|--------------------|-------------------|
| DMN2024UFDF-7  | 7                  | 3,000             |
| DMN2024UFDF-13 | 13                 | 10,000            |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and l ead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**

Site1



OA = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

| Year  | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code  | F    | G    | Н    |      | J    | К    | L    | М    | Ν    | 0    | Р    | R    |
|       |      |      |      |      |      |      |      |      |      |      |      |      |
| Month | Jan  | Feb  | Mar  | Apr  | Мау  | Jun  | Jul  | Aug  | Sep  | Oct  | Nov  | Dec  |

Site 2



OA = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

| Year | 2018 | 2019 | 2020 | 2021  | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 |
|------|------|------|------|-------|------|------|------|------|------|------|------|------|
| Code | 8    | 9    | 0    | 1     | 2    | 3    | 4    | 5    | 6    | 7    | 8    | 9    |
|      |      |      |      |       |      |      |      |      |      |      |      |      |
| Week | 1-26 |      |      | 27-52 |      |      |      | 53   |      |      |      |      |
| Code | A-Z  |      |      | a-z   |      |      |      | Z    |      |      |      |      |
|      |      |      |      |       |      |      |      |      |      |      |      |      |

| Internal Code | Sun | Mon | Tue | Wed | Thu | Fri | Sat |
|---------------|-----|-----|-----|-----|-----|-----|-----|
| Code          | Т   | U   | V   | W   | Х   | Y   | Z   |



### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic                                    | Symbol           | Value  | Unit |            |    |
|---|------------------|--|------|------------|----|
| Drain-Source Voltage                              |                  | VDSS   | 20   | V          |    |
| Gate-Source Voltage                               | V <sub>GSS</sub> | ±10  | V    |            |    |
| Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V | Steady<br>State  | T <sub>A</sub> = +25°C<br>T <sub>A</sub> = +70°C | lo   | 7.1<br>5.6 | A  |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1% | .)               |  | Ідм  | 40         | A  |
| Continuous Source-Drain Diode Current             |                  | ls   | 2.6  | A          |    |
| Avalanche Current (Note 7) L = 0.1mH              | las              | 12   | A    |            |    |
| Avalanche Energy (Note 7) L = 0.1mH               |                  |  | Eas  | 8          | mJ |

## **Thermal Characteristics**

| Characteristic                                   |                        | Symbol   | Value       | Unit |
|--|------------------------|----------|-------------|------|
| Total Power Dissipation (Note 5)                 | T <sub>A</sub> = +25°C | PD       | 0.96        | W    |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State           | Roja     | 130         | °C/W |
| Total Power Dissipation (Note 6)                 | T <sub>A</sub> = +25°C | PD       | 1.67        | W    |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State           | Reja     | 75          | 80 M |
| Thermal Resistance, Junction to Case (Note 6)    | Rejc                   | 16       | °C/W        |      |
| Operating and Storage Temperature Range          |                        | TJ, TSTG | -55 to +150 | °C   |

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                             | Symbol              | Min | Тур  | Max | Unit  | Test Condition                                  |
|--|---------------------|-----|------|-----|-------|---|
| OFF CHARACTERISTICS (Note 8)               |                     |     |      |     |       | ·   |
| Drain-Source Breakdown Voltage             | BV <sub>DSS</sub>   | 20  | _    | —   | V     | $V_{GS} = 0V, I_D = 250 \mu A$                  |
| Zero Gate Voltage Drain Current TJ = +25°C | IDSS                | —   | —    | 1   | μA    | $V_{DS} = 20V, V_{GS} = 0V$                     |
| Gate-Source Leakage                        | I <sub>GSS</sub>    | —   | —    | ±10 | μA    | $V_{GS} = \pm 8V, V_{DS} = 0V$                  |
| ON CHARACTERISTICS (Note 8)                |                     |     | -    |     | -     |   |
| Gate Threshold Voltage                     | V <sub>GS(TH)</sub> | 0.5 | _    | 1.0 | V     | $V_{DS} = V_{GS}, I_D = 250 \mu A$              |
|  |                     |     | 15   | 22  |       | $V_{GS} = 4.5V, I_D = 4A$                       |
| Static Drain-Source On-Resistance          | R <sub>DS(ON)</sub> | _   | 17   | 26  | mΩ    | VGS = 2.5V, ID = 4A                             |
| Static Drain-Source On-Resistance          | NDS(ON)             |     | 20   | 36  | 11152 | VGS = 1.8V, ID = 4A                             |
|  |                     |     | 23   | 50  |       | VGS = 1.5V, ID = 4A                             |
| Diode Forward Voltage                      | Vsd                 | —   | 0.7  | 1.0 | V     | $V_{GS} = 0V$ , $I_{S} = 5A$                    |
| DYNAMIC CHARACTERISTICS (Note 9)           |                     |     | -    |     | -     |   |
| Input Capacitance                          | Ciss                | —   | 647  | —   |       |   |
| Output Capacitance                         | Coss                | —   | 78   | —   | pF    | $V_{DS} = 10V$ , $V_{GS} = 0V$ ,<br>f = 1.0MHz  |
| Reverse Transfer Capacitance               | Crss                | —   | 38   | —   |       |   |
| Gate Resistance                            | Rg                  | —   | 400  | —   | Ω     | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$            |
| Total Gate Charge (V <sub>GS</sub> = 4.5V) | Qg                  | —   | 6.5  | —   |       |   |
| Total Gate Charge (V <sub>GS</sub> = 10V)  | Qg                  | _   | 14.8 | _   | nC    |   |
| Gate-Source Charge                         | Qgs                 | —   | 1.1  | —   | nC    | $V_{DS} = 10V, I_{D} = 6.5A$                    |
| Gate-Drain Charge                          | Q <sub>gd</sub>     | —   | 1.7  | —   |       |   |
| Turn-On Delay Time                         | td(ON)              | —   | 98   | —   |       |   |
| Turn-On Rise Time                          | tR                  | —   | 140  | —   |       | $V_{DS} = 10V, V_{GS} = 4.5V,$                  |
| Turn-Off Delay Time                        | t <sub>D(OFF)</sub> | —   | 1024 | —   | ns    | $R_G = 6\Omega$ , $R_L = 10\Omega$ , $I_D = 1A$ |
| Turn-Off Fall Time                         | tF                  | —   | 434  | —   | 1     |   |
| Reverse Recovery Time                      | trr                 | —   | 245  | —   | ns    | IF = 1A, di/dt = 100A/µs                        |
| Reverse Recovery Charge                    | QRR                 | l — | 149  | l — | nC    | I <sub>F</sub> = 1A, di/dt = 100A/µs            |

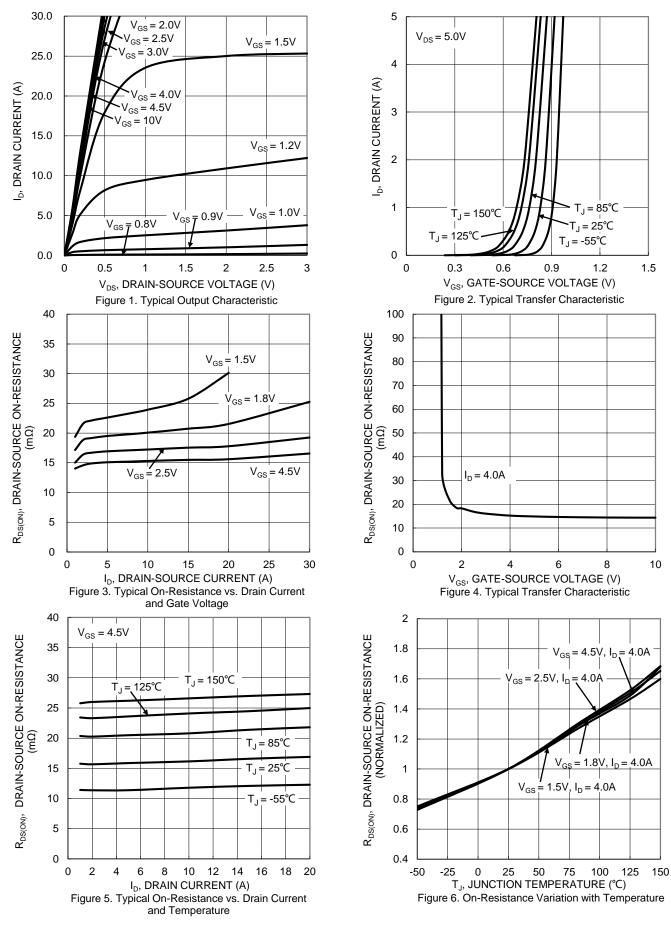
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

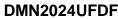


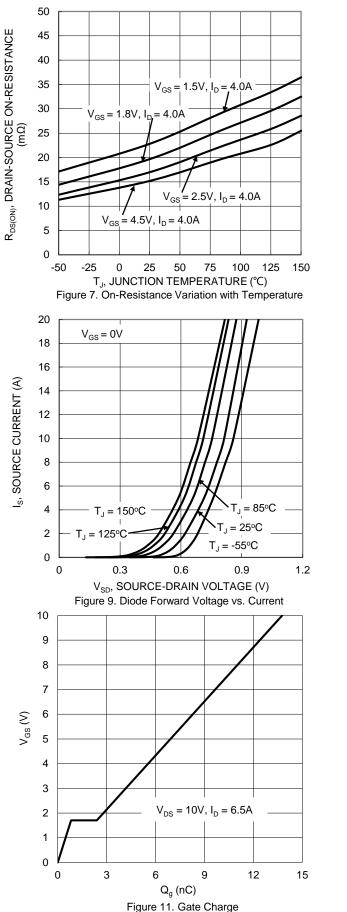
## DMN2024UFDF

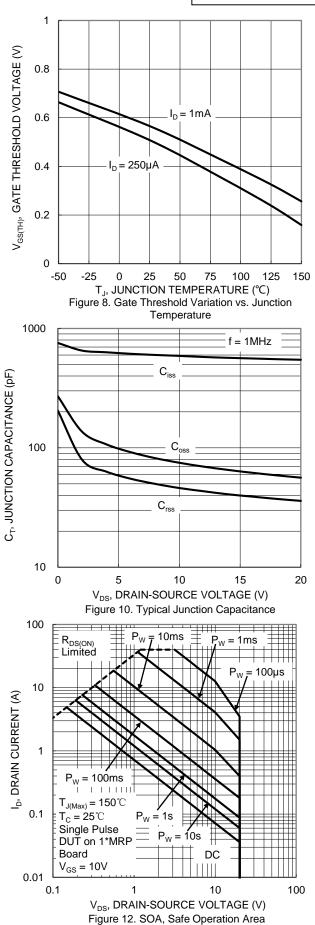


DMN2024UFDF Datasheet number: DS40595 Rev. 8 - 2



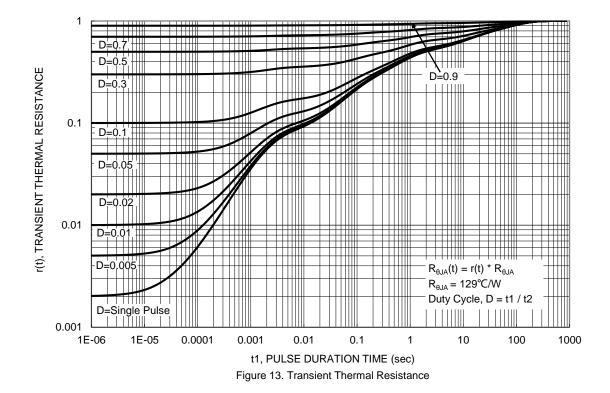






DMN2024UFDF Datasheet number: DS40595 Rev. 8 - 2

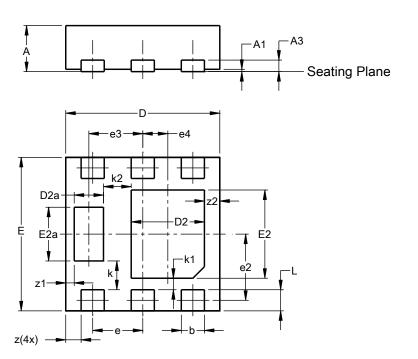






### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

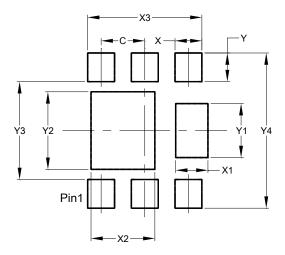


|       | U-DFN2020-6       |          |      |  |  |  |  |  |  |
|-------|-------------------|----------|------|--|--|--|--|--|--|
|       |                   | be F)    |      |  |  |  |  |  |  |
| Dim   | Min               | Max      | Тур  |  |  |  |  |  |  |
| Α     | 0.57              | 0.63     | 0.60 |  |  |  |  |  |  |
| A1    | 0.00              | 0.05     | 0.03 |  |  |  |  |  |  |
| A3    | -                 | -        | 0.15 |  |  |  |  |  |  |
| b     | 0.25              | 0.35     | 0.30 |  |  |  |  |  |  |
| D     | 1.95              | 2.05     | 2.00 |  |  |  |  |  |  |
| D2    | 0.85              | 1.05     | 0.95 |  |  |  |  |  |  |
| D2a   | 0.33              | 0.43     | 0.38 |  |  |  |  |  |  |
| E     | 1.95              | 2.05     | 2.00 |  |  |  |  |  |  |
| E2    | 1.05              | 1.25     | 1.15 |  |  |  |  |  |  |
| E2a   | 0.65              | 0.75     | 0.70 |  |  |  |  |  |  |
| е     |                   | 0.65 BS  | С    |  |  |  |  |  |  |
| e2    | (                 | ).863 BS | SC   |  |  |  |  |  |  |
| e3    |                   | 0.70 BS  | С    |  |  |  |  |  |  |
| e4    |                   | ).325 BS |      |  |  |  |  |  |  |
| k     |                   | 0.37 BS  | С    |  |  |  |  |  |  |
| k1    |                   | 0.15 BS  | С    |  |  |  |  |  |  |
| k2    |                   | 0.36 BS  | С    |  |  |  |  |  |  |
| L     | 0.225 0.325 0.275 |          |      |  |  |  |  |  |  |
| z     |                   | 0.20 BS  | С    |  |  |  |  |  |  |
| z1    | (                 | ).110 BS | SC   |  |  |  |  |  |  |
| z2    |                   | 0.20 BS  | С    |  |  |  |  |  |  |
| All C | Dimens            | ions in  | mm   |  |  |  |  |  |  |

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN2020-6 (Type F)



| Dimensions | Value   |
|------------|---------|
| Dimensions | (in mm) |
| С          | 0.650   |
| Х          | 0.400   |
| X1         | 0.480   |
| X2         | 0.950   |
| X3         | 1.700   |
| Y          | 0.425   |
| Y1         | 0.800   |
| Y2         | 1.150   |
| Y3         | 1.450   |
| Y4         | 2.300   |

#### U-DFN2020-6 (Type F)



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